

International  
**IR** Rectifier

Bulletin I25158 rev. B 01/94

**ST300S SERIES**

**PHASE CONTROL THYRISTORS**

**Stud Version**

300A

**Features**

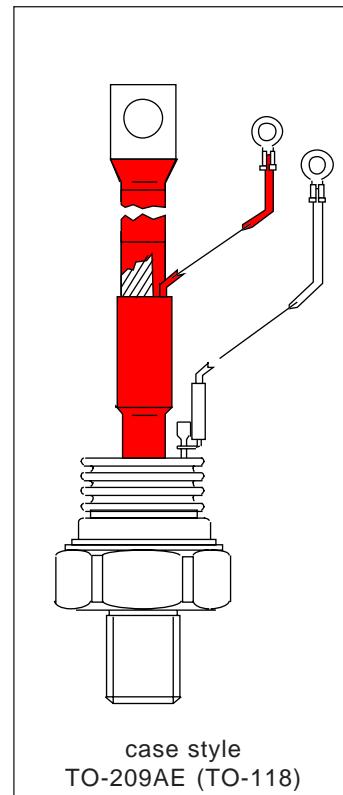
- Center amplifying gate
- Hermetic metal case with ceramic insulator
- International standard case TO-209AE (TO-118)
- Threaded studs UNF 3/4 - 16UNF2A or ISO M24x1.5
- Compression Bonded Encapsulation for heavy duty operations such as severe thermal cycling

**Typical Applications**

- DC motor controls
- Controlled DC power supplies
- AC controllers

**Major Ratings and Characteristics**

Parameters	ST300S	Units
$I_{T(AV)}$	300	A
@ $T_c$	75	°C
$I_{T(RMS)}$	470	A
$I_{TSM}$	8000	A
@ 50Hz	8000	A
@ 60Hz	8380	A
$I^2t$	320	KA <sup>2</sup> s
@ 50Hz	320	KA <sup>2</sup> s
@ 60Hz	292	KA <sup>2</sup> s
$V_{DRM}/V_{RRM}$	400 to 2000	V
$t_q$	typical	100
		μs
$T_j$	- 40 to 125	°C



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### ELECTRICAL SPECIFICATIONS

#### Voltage Ratings

Type number	Voltage Code	$V_{DRM}/V_{RRM}$ , max. repetitive peak and off-state voltage V	$V_{RSM}$ , maximum non-repetitive peak voltage V	$I_{DRM}/I_{RRM}$ max. @ $T_J = T_{J \max}$ mA
ST300S	04	400	500	50
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	

#### On-state Conduction

Parameter	ST300S	Units	Conditions
$I_{T(AV)}$ @ Case temperature	300	A	180° conduction, half sine wave
	75	°C	
$I_{T(RMS)}$	470	A	DC @ 64°C case temperature
$I_{TSM}$ Max. peak, one-cycle non-repetitive surge current	8000	A	t = 10ms t = 8.3ms 100% $V_{RRM}$ reapplied
	8380		
	6730		
	7040		
$I^2t$ Maximum $I^2t$ for fusing	320	KA <sup>2</sup> s	t = 10ms t = 8.3ms 100% $V_{RRM}$ reapplied
	292		
	226		
	207		
$I^2/\tau$	3200	KA <sup>2</sup> /s	t = 0.1 to 10ms, no voltage reapplied
$V_{T(TO)1}$ Low level value of threshold voltage	0.97	V	(16.7% $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ ), $T_J = T_{J \max}$
$V_{T(TO)2}$ High level value of threshold voltage	0.98		( $I > \pi \times I_{T(AV)}$ ), $T_J = T_{J \max}$
$r_{t1}$ Low level value of on-state slope resistance	0.74	mΩ	(16.7% $\times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)}$ ), $T_J = T_{J \max}$
$r_{t2}$ High level value of on-state slope resistance	0.73		( $I > \pi \times I_{T(AV)}$ ), $T_J = T_{J \max}$
$V_{TM}$ Max. on-state voltage	1.66	V	$I_{pk} = 940A$ , $T_J = T_{J \max}$ , $t_p = 10ms$ sine pulse
$I_H$ Maximum holding current	600	mA	$T_J = 25^\circ C$ , anode supply 12V resistive load
$I_L$ Typical latching current	1000		

Switching

Parameter	ST300S	Units	Conditions
di/dt Max. non-repetitive rate of rise of turned-on current	1000	A/μs	Gate drive 20V, 20Ω, $t_r \leq 1\mu s$ $T_J = T_{J_{max}}$ , anode voltage $\leq 80\% V_{DRM}$
$t_d$ Typical delay time	1.0	μs	Gate current 1A, $di_g/dt = 1A/\mu s$ $V_d = 0.67\% V_{DRM}$ , $T_J = 25^\circ C$
$t_q$ Typical turn-off time	100		$I_{TM} = 550A$ , $T_J = T_{J_{max}}$ , $di/dt = 40A/\mu s$ , $V_R = 50V$ $dv/dt = 20V/\mu s$ , Gate 0V 100Ω, $t_p = 500\mu s$

Blocking

Parameter	ST300S	Units	Conditions
dv/dt Maximum critical rate of rise of off-state voltage	500	V/μs	$T_J = T_{J_{max}}$ linear to 80% rated $V_{DRM}$
$I_{RRM}$ Max. peak reverse and off-state leakage current	50	mA	$T_J = T_{J_{max}}$ , rated $V_{DRM}/V_{RRM}$ applied

Triggering

Parameter	ST300S	Units	Conditions
$P_{GM}$ Maximum peak gate power	10.0	W	$T_J = T_{J_{max}}$ , $t_p \leq 5ms$
$P_{G(AV)}$ Maximum average gate power	2.0		$T_J = T_{J_{max}}$ , $f = 50Hz$ , $d\% = 50$
$I_{GM}$ Max. peak positive gate current	3.0	A	$T_J = T_{J_{max}}$ , $t_p \leq 5ms$
$+V_{GM}$ Maximum peak positive gate voltage	20	V	$T_J = T_{J_{max}}$ , $t_p \leq 5ms$
$-V_{GM}$ Maximum peak negative gate voltage	5.0		
$I_{GT}$ DC gate current required to trigger	TYP. 200 100 50	MAX. - 200 -	mA $T_J = -40^\circ C$ $T_J = 25^\circ C$ $T_J = 125^\circ C$
$V_{GT}$ DC gate voltage required to trigger	2.5 1.8 1.1	- 3 -	V $T_J = -40^\circ C$ $T_J = 25^\circ C$ $T_J = 125^\circ C$
$I_{GD}$ DC gate current not to trigger	10.0	mA	
$V_{GD}$ DC gate voltage not to trigger	0.25	V	$T_J = T_{J_{max}}$ Max. gate current/ voltage not to trigger is the max. value which will not trigger any unit with rated $V_{DRM}$ anode-to-cathode applied

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### Thermal and Mechanical Specification

Parameter	ST300S	Units	Conditions
$T_J$	Max. operating temperature range	-40 to 125	
$T_{sg}$	Max. storage temperature range	-40 to 150	
$R_{thJC}$	Max. thermal resistance, junction to case	0.10	DC operation
$R_{thCS}$	Max. thermal resistance, case to heatsink	0.03	Mounting surface, smooth, flat and greased
T	Mounting torque, $\pm 10\%$	48.5 (425)	Nm (lbf-in)
wt	Approximate weight	535	g
Case style	TO - 209AE (TO-118)		See Outline Table

### $\Delta R_{thJC}$ Conduction

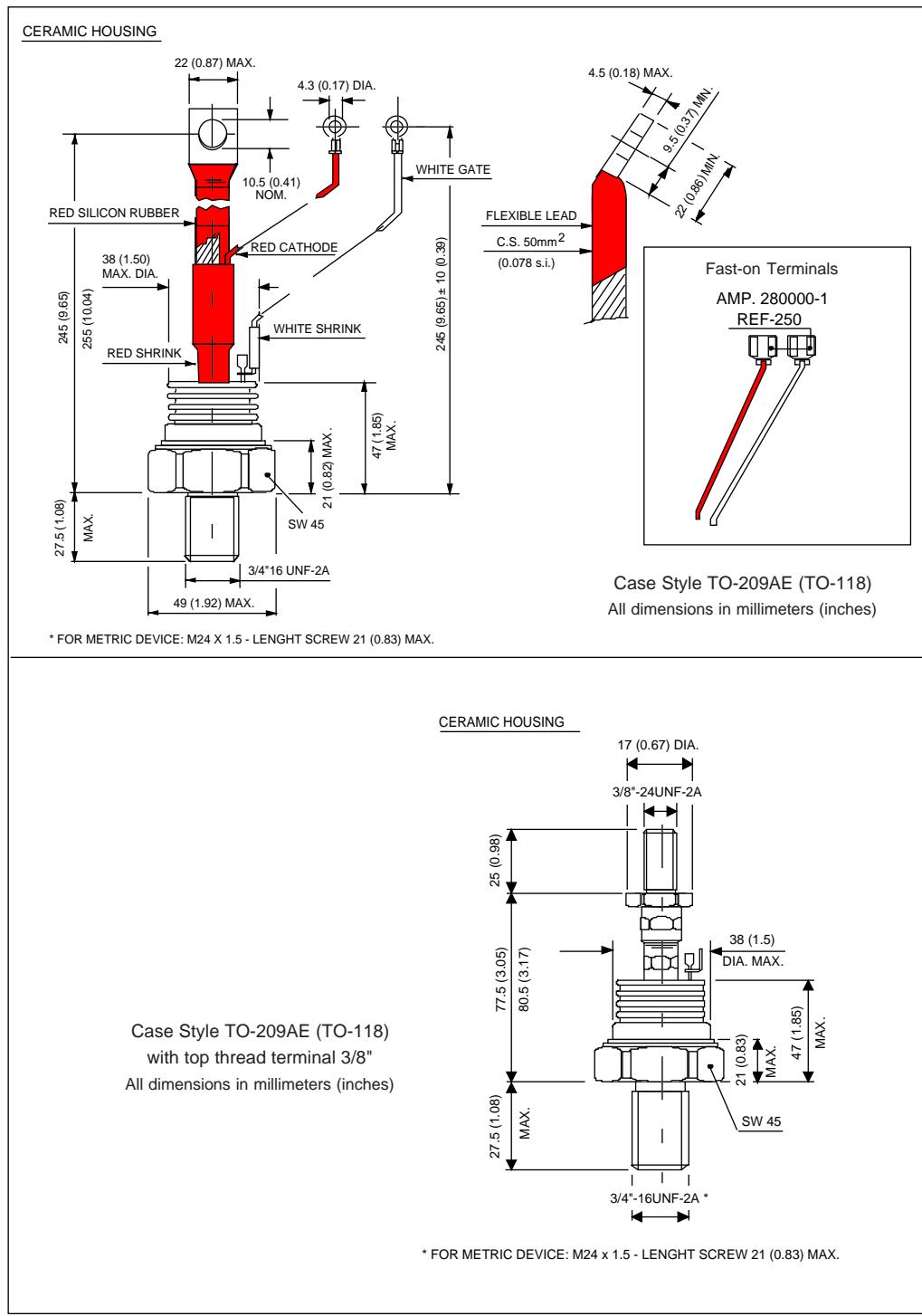
(The following table shows the increment of thermal resistance  $R_{thJC}$  when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.011	0.008	K/W	$T_J = T_{J \text{ max.}}$
120°	0.013	0.014		
90°	0.017	0.018		
60°	0.025	0.026		
30°	0.041	0.042		

### Ordering Information Table

Device Code	ST	30	0	S	20	P	0	
	1	2	3	4	5	6	7	8
<b>1</b>	- Thyristor							
<b>2</b>	- Essential part number							
<b>3</b>	- 0 = Converter grade							
<b>4</b>	- S = Compression bonding Stud							
<b>5</b>	- Voltage code: Code x 100 = $V_{RRM}$ (See Voltage Rating Table)							
<b>6</b>	- P = Stud base 16UNF threads							
	M = Stud base metric threads (M24 x 1.5)							
<b>7</b>	- 0 = Eyelet terminals (Gate and Auxiliary Cathode Leads)							
	1 = Fast - on terminals (Gate and Auxiliary Cathode Leads)							
	3 = Threaded top terminal 3/8" 24UNF-2A							
<b>8</b>	- Critical dv/dt: None = 500V/ $\mu$ sec (Standard value)							
	L = 1000V/ $\mu$ sec (Special selection)							

Outline Table



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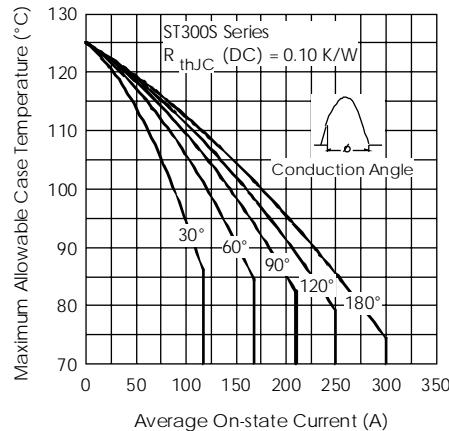


Fig. 1 - Current Ratings Characteristics

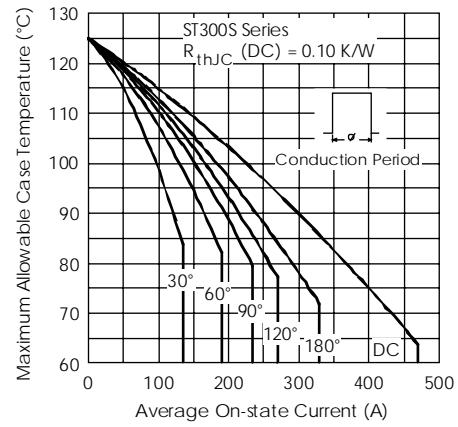


Fig. 2 - Current Ratings Characteristics

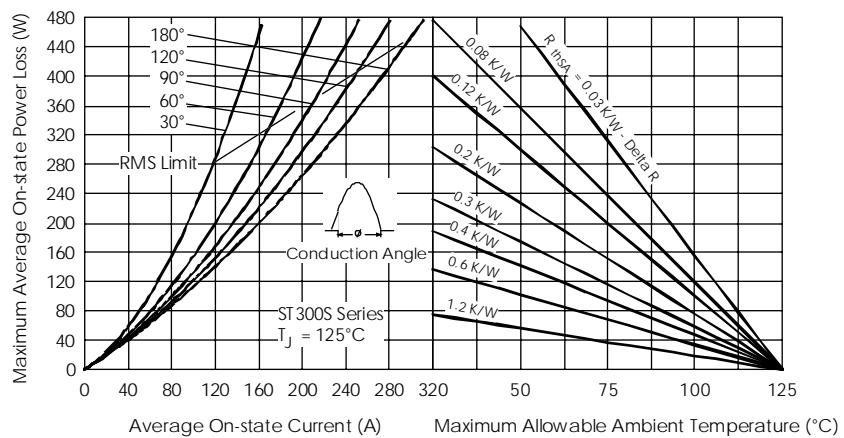


Fig. 3 - On-state Power Loss Characteristics

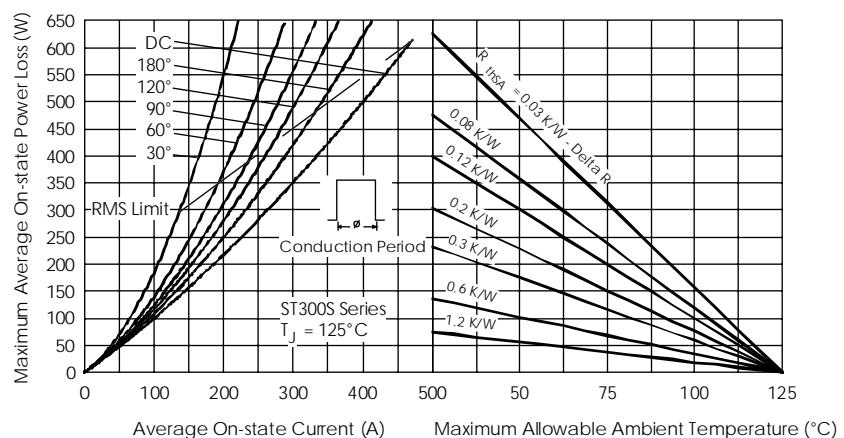


Fig. 4 - On-state Power Loss Characteristics

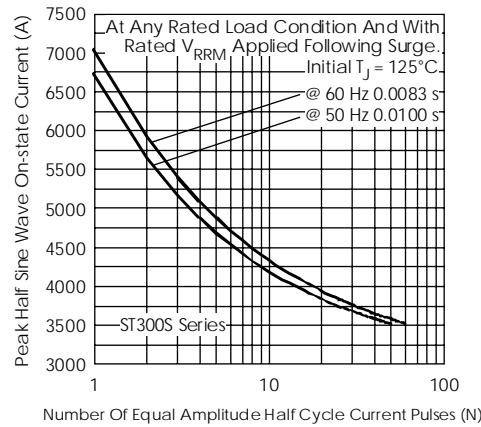


Fig. 5 - Maximum Non-Repetitive Surge Current

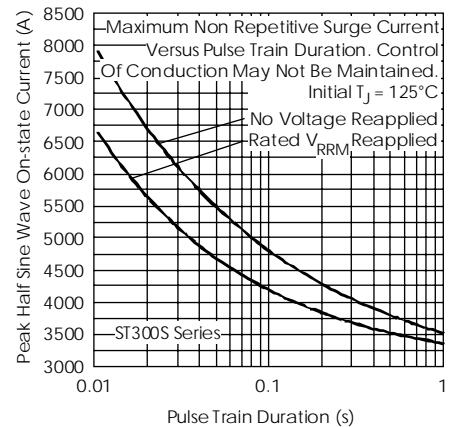


Fig. 6 - Maximum Non-Repetitive Surge Current

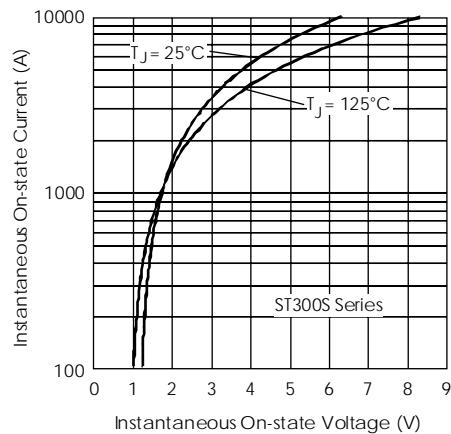


Fig. 7 - On-state Voltage Drop Characteristics

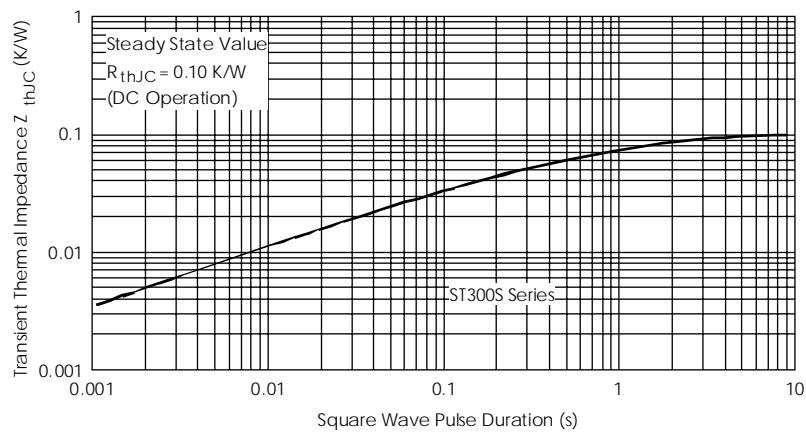


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristic

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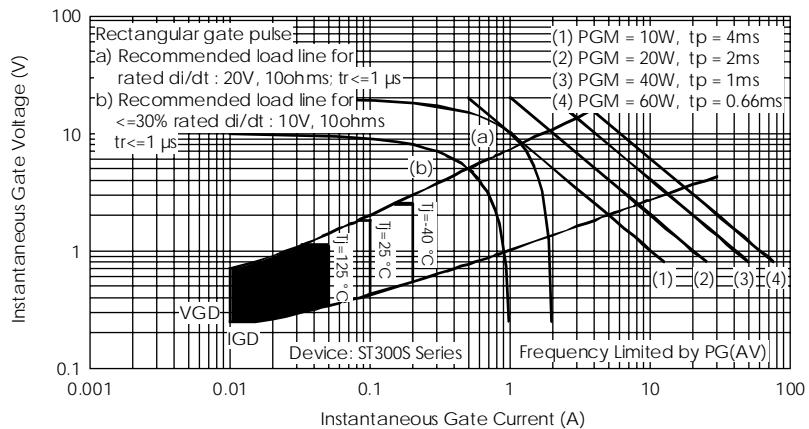


Fig. 9 - Gate Characteristics